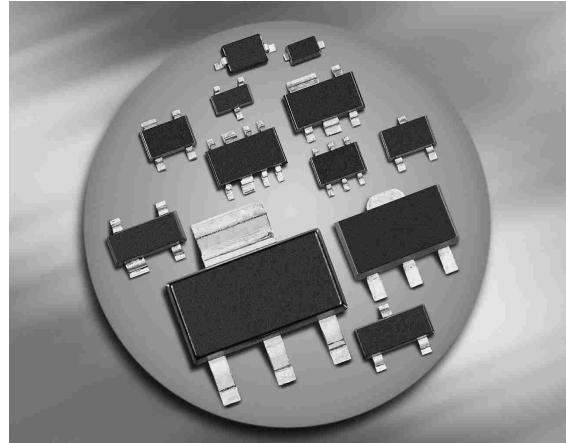


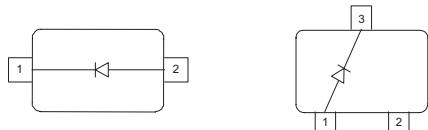
Silicon PIN Diode

- Current-controlled RF resistor
for switching and attenuating applications
- Frequency range 1 MHz ... 2 GHz
- Especially useful as antenna switch
in TV-sat tuners
- Very low harmonics



BA595
BA895

BA885



Type	Package	Configuration	L_S (nH)	Marking
BA595	SOD323	single	1.8	white R
BA885	SOT23	single	1.8	PA
BA895	SCD80	single	0.8	RA

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	50	V
Forward current	I_F	50	mA
Junction temperature	T_j	150	$^\circ\text{C}$
Operating temperature range	T_{op}	-55 ... 125	
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

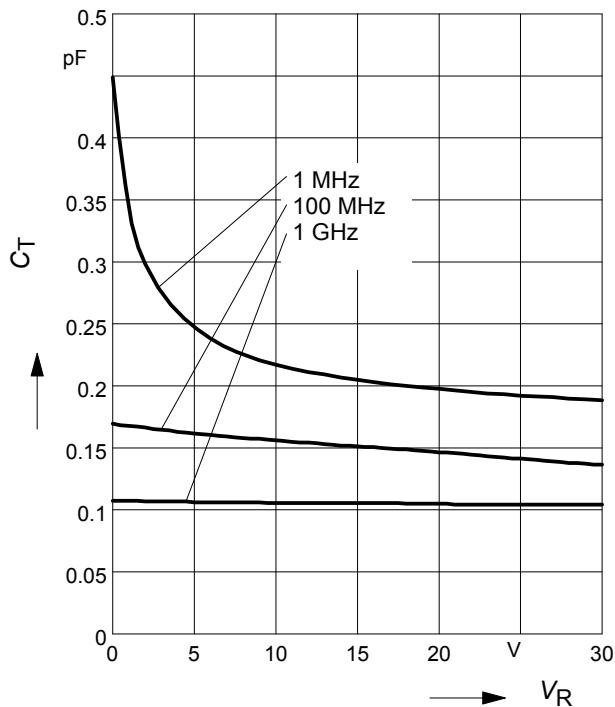
Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BA595, BA885	R_{thJS}	≤ 370	K/W
BA895		≤ 95	

¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance

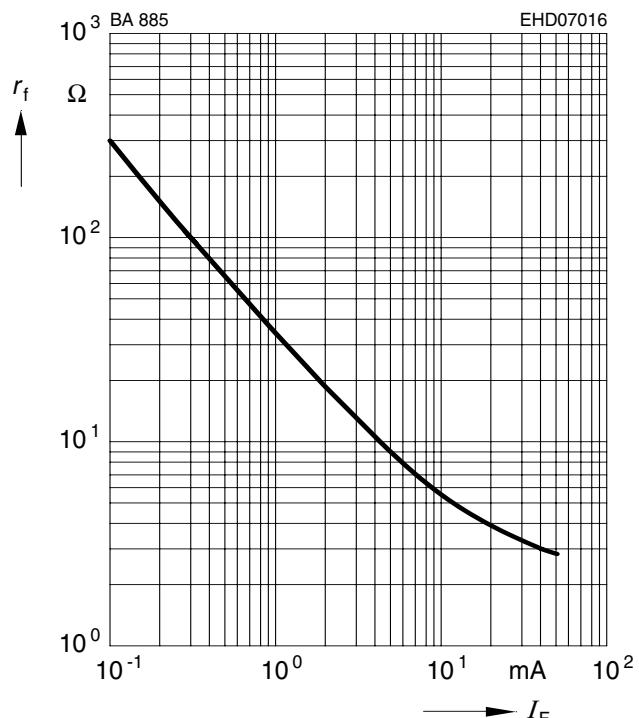
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current $V_R = 30 \text{ V}$	I_R	-	-	50	nA
Forward voltage $I_F = 50 \text{ mA}$	V_F	-	-	1.1	V
AC Characteristics					
Diode capacitance $V_R = 0 \text{ V}, f = 100 \text{ MHz}$ $V_R = 10 \text{ V}, f = 1 \text{ MHz}$	C_T	-	0.26	0.4	pF
Reverse parallel resistance $V_R = 1 \text{ V}, f = 100 \text{ MHz}$ $V_R = 0 \text{ V}, f = 1 \text{ GHz}$	R_P	-	100	-	kΩ
Forward resistance $I_F = 1.5 \text{ mA}, f = 100 \text{ MHz}$ $I_F = 10 \text{ mA}, f = 100 \text{ MHz}$	r_f	-	22	40	Ω
Charge carrier life time $I_F = 10 \text{ mA}, I_R = 6 \text{ mA}, \text{measured at } I_R = 3 \text{ mA}, R_L = 100 \Omega$	τ_{rr}	-	1600	-	ns
I-region width	W_I	-	130	-	μm

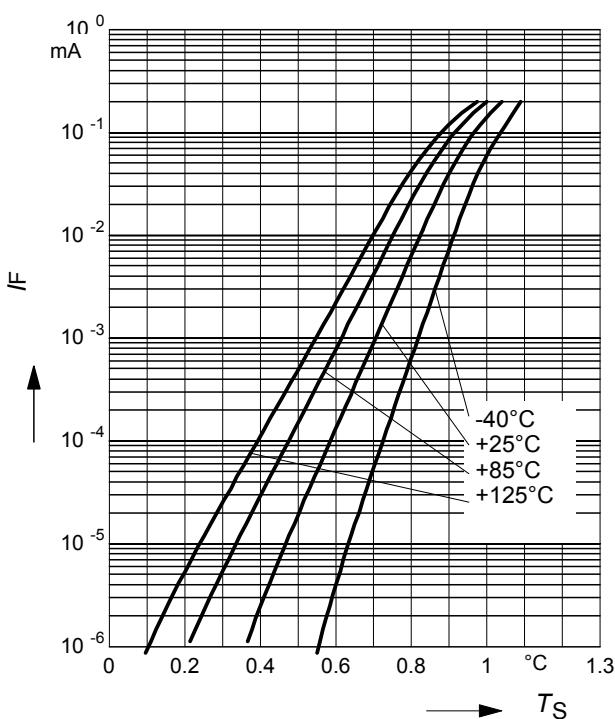
Diode capacitance $C_T = f (V_R)$
 f = Parameter



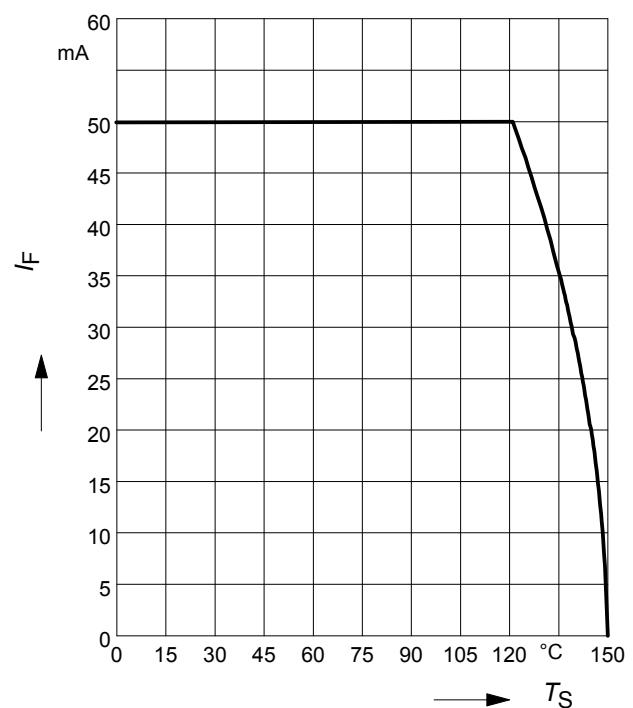
Forward resistance $r_f = f (I_F)$
 f = Parameter



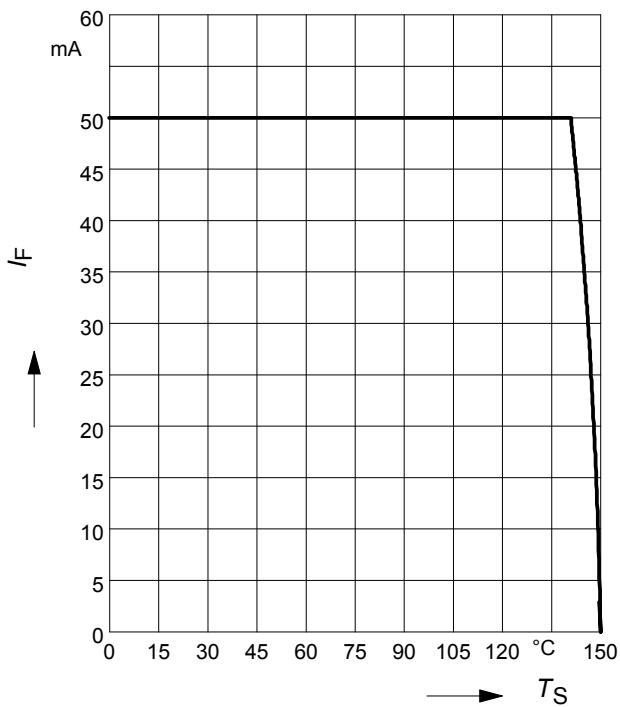
Forward current $I_F = f (V_F)$
 T_A = Parameter



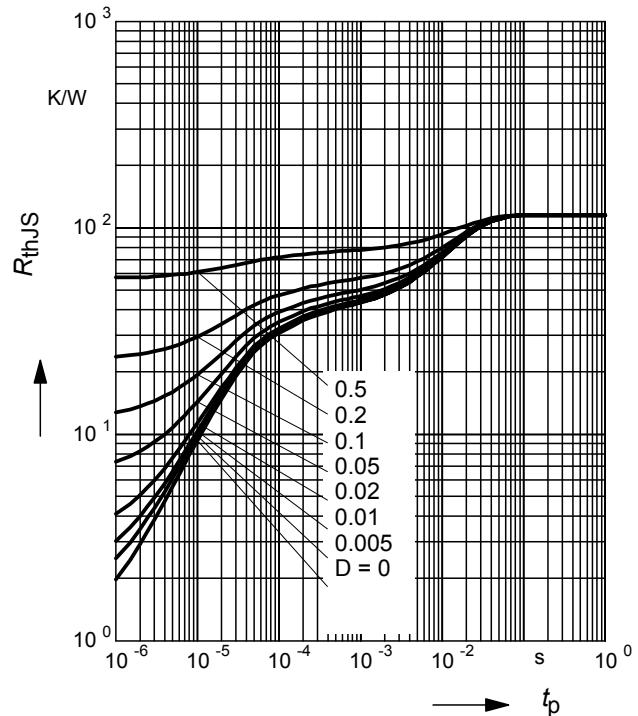
Forward current $I_F = f (T_S)$
BA595



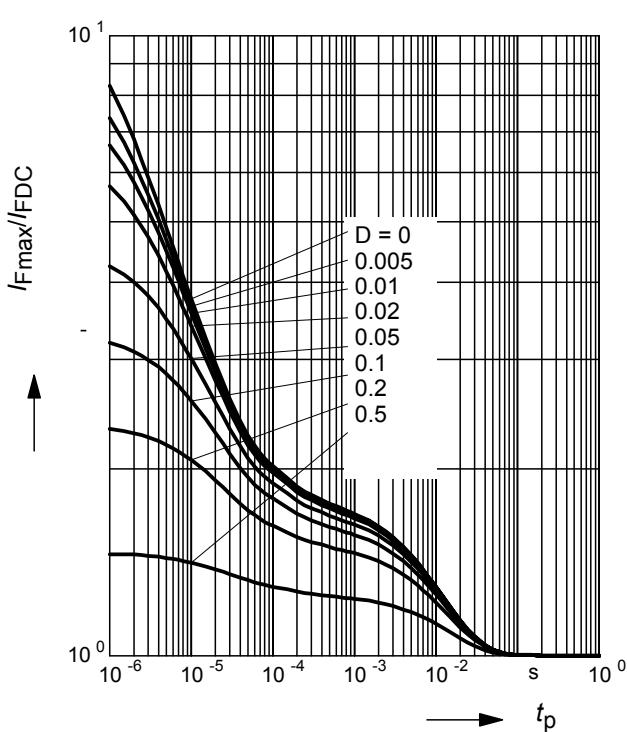
Forward current $I_F = f(T_S)$
BA895



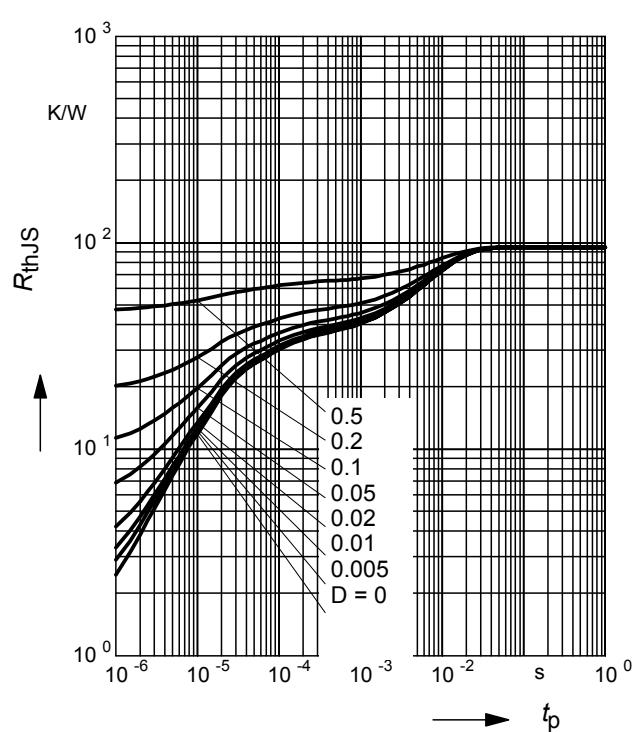
Permissible Puls Load $R_{thJS} = f(t_p)$
BA595



Permissible Pulse Load
 $I_{Fmax}/I_{FDC} = f(t_p)$
BA595



Permissible Puls Load $R_{thJS} = f(t_p)$
BA595



Permissible Pulse Load

$$I_{F\max} / I_{FDC} = f(t_p)$$

BA895

